

AFE7954 クワッド RF サンプリング 12GSPS D/A コンバータ (DAC)

1 特長

- データシート全体のご請求
- クワッド RF サンプリング 12GSPS DAC
- 最大 RF 信号帯域幅:
 - 4TX: 1200MHz または
 - 2TX: 2400MHz
- RF 周波数範囲: 600MHz ~ 12GHz
- デジタル・ステップ・アッテネータ (DSA):
 - TX: 40dB レンジ、0.125dB ステップ
- シングルまたはデュアル・バンド DUC
- TX に対応する 16 個の NCO
- DAC の内部 PLL / VCO、または DAC サンプル・レートでの外部クロックを選択可能
- SerDes データ・インターフェイス:
 - JESD204B、JESD204C 適合
 - 最高 29.5Gbps を発揮する 8 つの SerDes トランシーバ
 - サブクラス 1 のマルチデバイス同期
- パッケージ: 17mm × 17mm FCBGA、0.8mm ピッチ

2 アプリケーション

- レーダー
- 追尾フロント・エンド
- 防衛無線
- 戦術通信網
- ワイヤレス通信テスト

3 概要

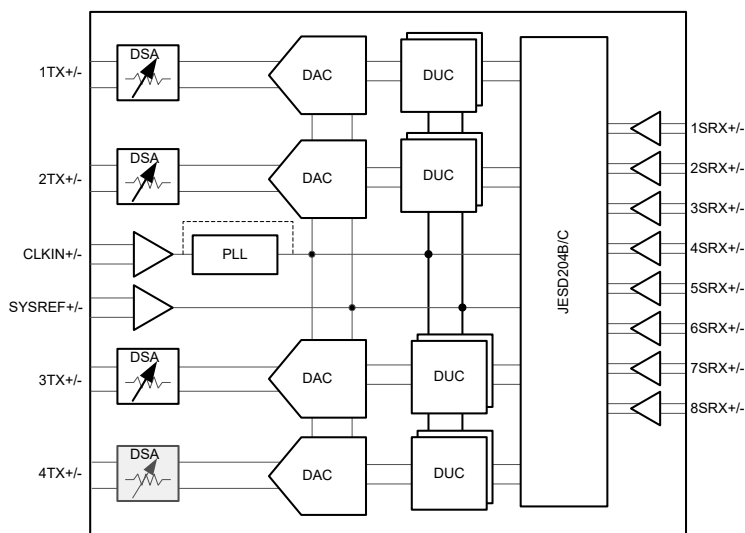
AFE7954 は、高性能、広帯域幅のクワッド・チャンネル RF サンプリング DAC です。このデバイスは、最大 12GHz で動作するため、追加の周波数変換段を必要とせず、L、S、C、X バンドの周波数範囲について直接 RF サンプリングが可能です。こうした密度と柔軟性の向上により、多くのチャンネル数を持つマルチミッション・システムが可能になります。

信号パスは、4 個の DAC (TX) で最大 1200MHz の信号帯域幅、または 2 個の DAC で 2400MHz を実現する、補間およびデジタル昇圧変換オプションをサポートしています。DUC の出力は、2 次ナイキスト動作を拡張する混在モード出力方式で 12GSPS の DAC (D/A コンバータ) を駆動します。DAC 出力は、40dB レンジ、1dB アナログ・ステップ、0.125dB デジタル・ステップの可変ゲイン・アンプ (TX DSA) を内蔵しています。

パッケージ情報

部品番号	パッケージ (1)	パッケージ・サイズ (2)
AFE7954	FC-BGA	17mm × 17mm

- 詳細については、「メカニカル、パッケージ、および注文情報」を参照してください。
- パッケージ・サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



機能ブロック図



Table of Contents

1 特長	1	6.7 Digital Electrical Characteristics.....	15
2 アプリケーション	1	6.8 Power Supply Electrical Characteristics.....	17
3 概要	1	6.9 Timing Requirements.....	19
4 概要 (続き)	3	6.10 Switching Characteristics.....	20
5 Revision History	3	7 Device and Documentation Support	21
6 Specifications	4	7.1 ドキュメントの更新通知を受け取る方法.....	21
6.1 Absolute Maximum Ratings.....	4	7.2 サポート・リソース.....	21
6.2 ESD Ratings.....	4	7.3 Trademarks.....	21
6.3 Recommended Operating Conditions.....	5	7.4 静電気放電に関する注意事項.....	21
6.4 Thermal Information AFE79xx.....	5	7.5 用語集.....	21
6.5 Transmitter Electrical Characteristics.....	6	8 Mechanical, Packaging, and Orderable Information..	21
6.6 PLL/VCO/Clock Electrical Characteristics.....	13		

4 概要 (続き)

各レシーバ・チェーンは、3GSPS の ADC (A/D コンバータ) に接続された 25dB レンジの DSA (デジタル・ステップ・アッテネータ) を備えています。各レシーバ・チャンネルは、外部または内部の自律的な AGC (自動ゲイン制御) を補助するためのアナログ・ピーク電力検出器とさまざまなデジタル電力検出器、およびデバイスの信頼性を確保するための RF 過負荷検出器を備えています。柔軟なデシメーション・オプションによりデータ帯域幅を最適化でき、FB パスなしの 4 つの RX では最高 1200MHz、2 つの FB パス付き (それぞれ 1200MHz の帯域幅) では最高 600MHz が得られます。

5 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

DATE	REVISION	NOTES
July 2023	*	Initial Release

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply Voltage Range	DVDD0P9, VDDT0P9	-0.3	1.2	V
	VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2PLL, VDD1P2PLLCLKREF, VDD1P2FB, VDD1P2FBCML, VDD1P2RXCML	-0.3	1.4	V
	VDD1P8RX, VDD1P8RXCLK, VDD1P8TX, VDD1P8TXDAC, VDD1P8TXENC, VDD1P8PLL, VDD1P8PLLVCO, VDD1P8FB, VDD1P8FBCML, VDD1P8GPIO, VDDA1P8	-0.5	2.1	V
Pin Voltage Range	{1/2/3/4}TXOUT+/-	-0.5	VDDTX1P8+0.3	V
	REFCLK+/-, SYSREF+/-	-0.3	1.4	V
	{1:8}SRX+/-	-0.3	1.4	V
	GPIO{B/C/D/E}x, SPICLK, SPISDIO, SPISDO, SPISEN, RESETZ, BISTB0, BISTB1	-0.5	VDD1P8GPIO + 0.3	V
	IFORCE, VSENSE	-0.3	VDDCLK1P8 + 0.3	V
	SRDAMUX1, SRDAMUX2	-0.3	VDDA1P8+0.3	V
Peak Input Current	any input		20	mA
T _J	Junction temperature		150	°C
T _{stg}	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	1000	V
		Charged device model (CDM), per ANSI/ESDA/ JEDEC JS-002, all pins	150	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
DVDD0P9, VDDT0P9	Supply voltage 0.9V	0.9	0.925	0.95	V
VDD1P2{RX/TXCLK/TXENC/FB/PLL/ PLLCLKREF/FBCML/RXCML}	Supply voltage 1.2V	1.15	1.2	1.25	V
VDD1P8{RX/RXCLK/TX/TXDAC/ TXENC/PLL/PLLVCO/FB/FBCLK/ GPIO}, VDDA1P8	Supply voltage 1.8V	1.75	1.8	1.85	V
T _A	Ambient temperature	-40		85	°C
T _J	Operating Junction Temperature			110 ⁽¹⁾	°C
	Maximum Operating Junction Temperature	125			°C

- (1) Prolonged use at or above this junction temperature can increase the device failure-in-time (FIT) rate. Refer to [SBAA403 application note](#) for additional details

6.4 Thermal Information AFE79xx

THERMAL METRIC ⁽¹⁾		17mmx17mm FC-BGA	UNIT
		400 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	16.2	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	0.42	°C/W
R _{θJB}	Junction-to-board thermal resistance	4.85	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.12	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	4.6	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Transmitter Electrical Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DAC_{RES}	DAC resolution			14		bits
f_{RFout}	RF output frequency range	$f_{\text{DAC}} = 12 \text{ GSPS}, 1^{\text{st}} \text{ Nyquist}$	600		6000	MHz
		$f_{\text{DAC}} = 12 \text{ GSPS}, 2^{\text{nd}} \text{ Nyquist}$	6000		12000	
		$f_{\text{DAC}} = 9 \text{ GSPS}, 1^{\text{st}} \text{ Nyquist}$	600		4500	
		$f_{\text{DAC}} = 9 \text{ GSPS}, 2^{\text{nd}} \text{ Nyquist}$	4500		9000	
		$f_{\text{DAC}} = 6 \text{ GSPS}, 1^{\text{st}} \text{ Nyquist}$	600		3000	
		$f_{\text{DAC}} = 6 \text{ GSPS}, 2^{\text{nd}} \text{ Nyquist}$	3000		6000	
$P_{\text{max_FS}}$	Max Full Scale Output Power, max gain 1 tone, at device pins	$f_{\text{out}} = 850 \text{ MHz}, f_{\text{DAC}} = 5898.24 \text{ MSPS}, -0.5\text{dBFS}$		4.2		dBm
		$f_{\text{out}} = 1800 \text{ MHz}, f_{\text{DAC}} = 5898.24 \text{ MSPS}, -0.5\text{dBFS}$		4.6		dBm
		$f_{\text{out}} = 2600 \text{ MHz}, f_{\text{DAC}} = 8847.36 \text{ MSPS}, -0.5\text{dBFS}$		4.0		dBm
		$f_{\text{out}} = 3500 \text{ MHz}, -0.5\text{dBFS}$		3.9		dBm
		$f_{\text{out}} = 4900 \text{ MHz}, -0.5\text{dBFS}$		3.1		dBm
		$f_{\text{out}} = 3500 \text{ MHz}, f_{\text{DAC}} = 5898.24 \text{ MSPS}, -0.5\text{dBFS}, \text{straight mode}$		1.0		dBm
		$f_{\text{out}} = 4900 \text{ MHz}, f_{\text{DAC}} = 5898.24 \text{ MSPS}, -0.5\text{dBFS}, \text{straight mode}$		0.1		dBm
		$f_{\text{out}} = 4900 \text{ MHz}, f_{\text{DAC}} = 8847.36 \text{ MSPS}, -0.5\text{dBFS}, \text{straight mode}$		-0.7		dBm
		$f_{\text{out}} = 8100 \text{ MHz}, -0.1\text{dBFS}, \text{mixed mode}$		-2.8		dBm
$f_{\text{out}} = 9600 \text{ MHz}, -0.1\text{dBFS}, \text{mixed mode}$		-4.3		dBm		
R_{TERM}	Output termination resistor	Default setting		50		Ω
$\text{ATT}_{\text{range}}$	DSA Attenuation range			40		dB
ATT_{step}	DSA Analog Attenuation step			1.0		dB
	DSA Attenuation step accuracy (DNL)	$0 < \text{Atten} < 40\text{dB}, \text{before calibration}$		± 0.2		dB
	DSA Attenuation step accuracy (DNL)	$0 < \text{Atten} < 40\text{dB}, \text{after calibration}$		± 0.1		dB
$\text{ATT}_{\text{phase-err}}$	DSA Gain Steps Phase accuracy, any 8dB range	$f_{\text{out}} = 850\text{MHz}^{(2)}$		± 1		deg
		$f_{\text{out}} = 1800\text{MHz}^{(2)}$		± 1		deg
		$f_{\text{out}} = 2600\text{MHz}^{(2)}$		± 1		deg
		$f_{\text{out}} = 3500\text{MHz}^{(2)}$		± 1		deg
		$f_{\text{out}} = 4900\text{MHz}^{(2)}$		± 1		deg
		$f_{\text{out}} = 8100\text{MHz}^{(2)}$		± 2		deg
G_{flat}	Gain flatness	any 20MHz		0.1		dB
		600MHz BW, $F_{\text{out}} < 4.9\text{G}$		1.2		

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
IMD3	3rd Order Intermodulation distortion, 2 tones at $f_{\text{IF}} \pm 10$ MHz	$f_{\text{out}} = 850\text{MHz}$, -7dBFS each tone		-66		dBc
		$f_{\text{out}} = 1800\text{MHz}$, -7dBFS each tone		-63		dBc
		$f_{\text{out}} = 2600\text{MHz}$, -7dBFS each tone		-62		dBc
		$f_{\text{out}} = 3500\text{MHz}$, -7dBFS each tone		-61		dBc
		$f_{\text{out}} = 4900\text{MHz}$, -7dBFS each tone		-57		dBc
		$f_{\text{out}} = 8100\text{MHz}$, -7dBFS each tone		-55		dBc
		$f_{\text{out}} = 9600\text{MHz}$, -7dBFS each tone		-52		dBc
		$f_{\text{out}} = 850\text{MHz}$, -13dBFS each tone		-74.4		dBc
		$f_{\text{out}} = 1800\text{MHz}$, -13dBFS each tone		-71.1		dBc
		$f_{\text{out}} = 2600\text{MHz}$, -13dBFS each tone		-73		dBc
		$f_{\text{out}} = 3500\text{MHz}$, -13dBFS each tone		-72		dBc
		$f_{\text{out}} = 4900\text{MHz}$, -13dBFS each tone		-67.8		dBc
		$f_{\text{out}} = 8100\text{MHz}$, -13dBFS each tone		-64		dBc
		$f_{\text{out}} = 9600\text{MHz}$, -13dBFS each tone		-68		dBc
SFDR	Spurious Free Dynamic Range (within Nyquist zone)	$f_{\text{out}} = 850$ MHz		50.8		dBc
		$f_{\text{out}} = 1800$ MHz		51.9		dBc
		$f_{\text{out}} = 2600$ MHz		42		dBc
		$f_{\text{out}} = 3500$ MHz		44		dBc
		$f_{\text{out}} = 4900$ MHz		46.1		dBc
$f_{\text{S}}/2 - f_{\text{OUT}}$	Interleaving Image	$f_{\text{DAC}} = 5898.24\text{MSPS}$, interleave mode		-51.9		dBc
		$f_{\text{DAC}} = 8847.36$ MSPS, interleave mode		-46.0		dBc
		$f_{\text{DAC}} = 11796.48\text{MSPS}$, interleave mode		-41		dBc
HD2	2nd Harmonic Distortion (within Nyquist zone)	$f_{\text{out}} = 850$ MHz		-49		dBc
		$f_{\text{out}} = 1800$ MHz		-53		dBc
		$f_{\text{out}} = 2600$ MHz		-50		dBc
		$f_{\text{out}} = 3500$ MHz		-48		dBc
		$f_{\text{out}} = 4900$ MHz		-47		dBc
		$f_{\text{out}} = 8100$ MHz		-50		dBc
		$f_{\text{out}} = 9600$ MHz		-53		dBc
		$f_{\text{out}} = 850$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-60		dBc
		$f_{\text{out}} = 1800$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-64		dBc
		$f_{\text{out}} = 2600$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-45		dBc
		$f_{\text{out}} = 3500$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-57		dBc
		$f_{\text{out}} = 4900$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-58		dBc
		$f_{\text{out}} = 8100$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-60		dBc
		$f_{\text{out}} = 9600$ MHz, $A_{\text{OUT}} = -12\text{dBFS}$		-62		dBc

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
HD3	3rd Harmonic Distortion (within Nyquist zone)	$f_{\text{out}} = 850\text{ MHz}$		-62		dBc
		$f_{\text{out}} = 1800\text{ MHz}$		-55		dBc
		$f_{\text{out}} = 2600\text{ MHz}$		-57		dBc
		$f_{\text{out}} = 3500\text{ MHz}$		-60		dBc
		$f_{\text{out}} = 4900\text{ MHz}$		-54		dBc
		$f_{\text{out}} = 8100\text{ MHz}$		-54		dBc
		$f_{\text{out}} = 9600\text{ MHz}$		-56		dBc
		$f_{\text{out}} = 850\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-80		dBc
		$f_{\text{out}} = 1800\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-79		dBc
		$f_{\text{out}} = 2600\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-77		dBc
		$f_{\text{out}} = 3500\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-77		dBc
		$f_{\text{out}} = 4900\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-78		dBc
		$f_{\text{out}} = 8100\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-82		dBc
		$f_{\text{out}} = 9600\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-80		dBc
HDn, n >= 4	Harmonic Distortion n >= 4 (within Nyquist zone)	$f_{\text{out}} = 850\text{ MHz}$		-81		dBc
		$f_{\text{out}} = 1800\text{ MHz}$		-88		dBc
		$f_{\text{out}} = 2600\text{ MHz}$		-86		dBc
		$f_{\text{out}} = 3500\text{ MHz}$		-79		dBc
		$f_{\text{out}} = 4900\text{ MHz}$		-86		dBc
		$f_{\text{out}} = 8100\text{ MHz}$		-87		dBc
		$f_{\text{out}} = 9600\text{ MHz}$		-85		dBc
		$f_{\text{out}} = 850\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-93		dBc
		$f_{\text{out}} = 1800\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-98		dBc
		$f_{\text{out}} = 2600\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-84		dBc
		$f_{\text{out}} = 3500\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 4900\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 8100\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 9600\text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
SFDR +/- 250 MHz	Spurious Free Dynamic Range within +/- 250 MHz	$f_{\text{out}} = 850\text{ MHz}$		68.5		dBc
		$f_{\text{out}} = 1800\text{ MHz}$		79.4		dBc
		$f_{\text{out}} = 2600\text{ MHz}$		77		dBc
		$f_{\text{out}} = 3500\text{ MHz}$		75		dBc
		$f_{\text{out}} = 4900\text{ MHz}$		76		dBc
		$f_{\text{out}} = 8100\text{ MHz}$		61		dBc
		$f_{\text{out}} = 9600\text{ MHz}$		64		dBc
$f_s/4$	Fixed Spur	$f_{\text{DAC}} = 5898.24\text{MSPS}$		-64		dBFS
		$f_{\text{DAC}} = 8847.36\text{MSPS}$		-75		dBFS
		$f_{\text{DAC}} = 11796.48\text{MSPS}$		-67		dBFS
$f_s/2$	Fixed Spur	$f_{\text{DAC}} = 5898.24\text{MSPS}$		-49		dBFS
		$f_{\text{DAC}} = 8847.36\text{MSPS}$		-48		dBFS
		$f_{\text{DAC}} = 11796.48\text{MSPS}$		-48		dBFS

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
3*f _S /4	Fixed Spur	2nd Nyquist, f _{DAC} = 5898.24MSPS		-76		dBFS
		2nd Nyquist, f _{DAC} = 8847.36MSPS		-89		dBFS
		2nd Nyquist, f _{DAC} = 11796.48MSPS		-63		dBFS
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier f _{out} = 0.85 GHz	Atten=0dB, Pout=-13dBFS		-68.5		dBc
		Atten=20dB, Pout=-13dBFS		-67.2		dBc
		Atten=28dB, Pout=-13dBFS		-64.5		dBc
		Atten=39dB, Pout=-13dBFS		-53.9		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier f _{out} = 1.8425 GHz	Atten=0dB, Pout=-13dBFS		-70.7		dBc
		Atten=20dB, Pout=-13dBFS		-68.3		dBc
		Atten=28dB, Pout=-13dBFS		-62.9		dBc
		Atten=39dB, Pout=-13dBFS		-52.0		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier f _{out} = 2.6 GHz	Atten=0dB, Pout=-13dBFS		-71		dBc
		Atten=20dB, Pout=-13dBFS		-68		dBc
		Atten=28dB, Pout=-13dBFS		-62		dBc
		Atten=39dB, Pout=-13dBFS		-51.3		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier f _{out} = 3.5 GHz	Atten=0dB, Pout=-13dBFS		-70		dBc
		Atten=20dB, Pout=-13dBFS		-67		dBc
		Atten=28dB, Pout=-13dBFS		-60		dBc
		Atten=39dB, Pout=-13dBFS		-49.8		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier f _{out} = 4.9 GHz	Atten=0dB, Pout=-13dBFS		-68.8		dBc
		Atten=20dB, Pout=-13dBFS		-65.9		dBc
		Atten=28dB, Pout=-13dBFS		-60.6		dBc
		Atten=39dB, Pout=-13dBFS		-49.5		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier f _{out} = 2.6 GHz	Atten=0dB, Pout=-13dBFS		-65		dBc
		Atten=20dB, Pout=-13dBFS		-62		dBc
		Atten=20dB, Pout=-13dBFS		-55		dBc
		Atten=39dB, Pout=-13dBFS		-44.3		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier f _{out} = 3.5 GHz	Atten=0dB, Pout=-13dBFS		-64		dBc
		Atten=20dB, Pout=-13dBFS		-59		dBc
		Atten=28dB, Pout=-13dBFS		-52		dBc
		Atten=39dB, Pout=-13dBFS		-41.1		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier f _{out} = 4.9 GHz	Atten=0dB, Pout=-13dBFS		-64.1		dBc
		Atten=20dB, Pout=-13dBFS		-60.4		dBc
		Atten=28dB, Pout=-13dBFS		-53.5		dBc
		Atten=39dB, Pout=-13dBFS		-42.5		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier f _{out} = 8.1 GHz	Atten=0dB, Pout=-13dBFS		-58		dBc
		Atten=20dB, Pout=-13dBFS		-53		dBc
		Atten=28dB, Pout=-13dBFS		-46		dBc
		Atten=39dB, Pout=-13dBFS		-36		dBc

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 9.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-57		dBc
		Atten=20dB, Pout=-13dBFS		-50		dBc
		Atten=28dB, Pout=-13dBFS		-42		dBc
		Atten=39dB, Pout=-13dBFS		-31		dBc
EVM	Error Vector Magnitude, 1x 20MHz E-TM3.1/3.1a, no ref. clock noise	$F_{\text{out}} = 0.85\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.2		%
		$F_{\text{out}} = 1.8425\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.3		%
		$F_{\text{out}} = 2.6\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.28		%
		$F_{\text{out}} = 3.5\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.38		%
		$F_{\text{out}} = 4.9\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.4		%
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 0.85\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-157.6		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-153.3		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-147.9		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-136.9		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 1.8\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-158.4		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-152.2		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-145.6		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-134.6		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 2.6\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-157		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-151		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-144		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-133.0		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $F_{\text{out}} = 3.5\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-158		dBFS/Hz
		Atten=20dB, Pout=-13dBFS		-150		dBFS/Hz
		Atten=28dB, Pout=-13dBFS		-143		dBFS/Hz
		Atten=39dB, Pout=-13dBFS		-131.8		dBFS/Hz

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
NSD _{dBFS}	Noise Spectral Density 20MHz offset $F_{\text{out}} = 4.9\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-155.5		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147.8		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140.8		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129.6		dBFS/ Hz
NSD _{dBFS}	Noise Spectral Density 50MHz offset $F_{\text{out}} = 8.1\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-153		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129		dBFS/ Hz
NSD _{dBFS}	Noise Spectral Density 50MHz offset $F_{\text{out}} = 9.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-152		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129		dBFS/ Hz
S22	Output Return Loss, <6GHz, +/- fc * 10%	with matching		-17		dB
	Output Return Loss, >8GHz, +/- fc * 10%	with matching		-10		dB
Isolation	Near Channel: 1TXOUT to 2TXOUT or 3TXOUT to 4TXOUT ⁽¹⁾	$f_{\text{out}} = 900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-49		dB
		$f_{\text{out}} = 1850\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-59		dB
		$f_{\text{out}} = 2600\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-65		dB
		$f_{\text{out}} = 3500\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-66		dB
		$f_{\text{out}} = 4900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-60		dB
		$f_{\text{out}} = 900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-90		dB
		$f_{\text{out}} = 1850\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-91		dB
		$f_{\text{out}} = 2600\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-93		dB
		$f_{\text{out}} = 3500\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-94		dB
		$f_{\text{out}} = 4900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-83		dB

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
PN _{TXADD}	Additive Phase Noise External Clock Mode ⁽³⁾	$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{Hz}$		-88		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 1\text{kHz}$		-102		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 10\text{kHz}$		-110		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{kHz}$		-123		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 1\text{MHz}$		-136		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 10\text{MHz}$		-143		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{MHz}$		-146		dBc/Hz

- (1) Measured with differential 50 ohm across TxP/M. The DC bias to 1.8V to each TxP/M at each pin remains and is not removed. Other external components on the TX paths are disconnected.
- (2) After DSA calibration procedure
- (3) Single side band, input clock phase noise subtracted.

6.6 PLL/VCO/Clock Electrical Characteristics

Typical values at TA = +25°C, full temperature range is T_{A,MIN} = -40°C to T_{J,MAX} = +110°C; Reference clock input frequency 491.52MHz (unless otherwise noted), f_{DAC} = f_{VCO}, f_{OUT} = f_{DAC}/4, normalized to f_{VCO}.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{VCO1}	VCO1 min frequency				7.2	GHz
	VCO1 max frequency		7.68			GHz
f _{VCO2}	VCO2 min frequency				8.8	GHz
	VCO2 max frequency		9.1			GHz
f _{VCO3}	VCO3 min frequency				9.7	GHz
	VCO3 max frequency		10.24			GHz
f _{VCO4}	VCO4 min frequency				11.6	GHz
	VCO4 max frequency		12.08			GHz
DIV _{DAC}	DAC sample rate divider			1, 2 or 3		
DIV _{FBAD} C	ADC sample rate divider from DAC sample rate			1, 2, 3, 4, 6 or 8		
DIV _{RXAD} C	ADC sample rate divider			1, 2, 3, 4, 6 or 8		
PN _{VCO}	Closed Loop Phase Noise F _{PLL} = 11.79848 GHz F _{REF} =491.52MHz	600kHz		-113		dBc/Hz
		800kHz		-116		dBc/Hz
		1MHz		-119		dBc/Hz
		1.8MHz		-125		dBc/Hz
		5MHz		-133		dBc/Hz
		50MHz		-141		dBc/Hz
	Closed Loop Phase Noise F _{PLL} =8.84736 GHz F _{REF} =491.52MHz	600kHz		-114		dBc/Hz
		800kHz		-118		dBc/Hz
		1MHz		-120		dBc/Hz
		1.8MHz		-127		dBc/Hz
		5MHz		-135		dBc/Hz
		50MHz		-142		dBc/Hz
	Closed Loop Phase Noise F _{PLL} = 9.8403 GHz F _{REF} =491.52MHz	600kHz		-113		dBc/Hz
		800kHz		-116		dBc/Hz
		1MHz		-119		dBc/Hz
		1.8MHz		-125		dBc/Hz
		5MHz		-134		dBc/Hz
		50MHz		-140		dBc/Hz
	Closed Loop Phase Noise F _{PLL} = 7.86432GHz F _{REF} =491.52MHz	600kHz		-116		dBc/Hz
		800kHz		-119		dBc/Hz
		1MHz		-122		dBc/Hz
		1.8MHz		-127		dBc/Hz
		5MHz		-136		dBc/Hz
		50MHz		-143		dBc/Hz
F _{rms}	Clock PLL integrated phase error ⁽¹⁾	f _{PLL} =11.79848 GHz, [1KHz, 100MHz]		-43.4		dBc/Hz
		f _{PLL} =8.8536 GHz, [1KHz, 100MHz]		-47.6		dBc/Hz
		f _{PLL} =9.8304 GHz, [1KHz, 100MHz]		-46.2		dBc/Hz
f _{PFD}	PFD frequency		100		500	MHz
PN _{pll_flat}	Normalized PLL flat Noise	f _{VCO} = 11796.48MHz		-226.5		dBc/Hz
F _{REF}	Input Clock frequency		0.1		12	GHz

6.6 PLL/VCO/Clock Electrical Characteristics (continued)

Typical values at TA = +25°C, full temperature range is TA,MIN = -40°C to TJ,MAX = +110°C; Reference clock input frequency 491.52MHz (unless otherwise noted), f_{DAC} = f_{VCO}, f_{OUT} = f_{DAC}/4, normalized to f_{VCO}.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{SS}	Input Clock level		0.6		1.8	Vppdiff
Coupling				AC Coupling Only		
	REFCLK input impedance ⁽²⁾	Parallel resistance		100		Ω
		Parallel capacitance		0.5		pF

- (1) Single Sideband, not including the reference clock contribution
(2) Refer to S11 data available from TI for impedance vs frequency

6.7 Digital Electrical Characteristics

Typical values at TA = +25°C, full temperature range is T_{A,MIN} = -40°C to T_{J,MAX} = +110°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CML SerDes Inputs [8:1]SRX+/-						
V _{SRDIFF}	SerDes Receiver Input Amplitude	differential	100		1200	mVpp
V _{SRCOM}	SerDes Input Common Mode		0.4	0.5	0.6	V
Z _{SRdiff}	SerDes Internal Differential Termination ⁽¹⁾			100		Ω
F _{SerDes}	SerDes Bit Rate	Full rate mode	19		29.5	Gbps
		Half rate mode	9.5		16.25	Gbps
		Quarter rate mode	4.75		8.125	Gbps
	Insertion Loss Tolerance ⁽²⁾	Serdes supply = 1.8V		25		dB
T _J	Total Jitter Tolerance				0.42	UI
CMOS I/O: GPIO{B/C/D/E}x, SPICLK, SPIDIO, SPISDO, SPISEN, RESETZ, BISTB0, BISTB1						
V _{IH}	High-Level Input Voltage		0.6×VDD1 P8GPIO			V
V _{IL}	Low-Level Input Voltage		0.4×VDD1 P8GPIO			V
I _{IH}	High-Level Input Current		-250		250	μA
I _{IL}	Low-Level Input Current		-250		250	μA
C _L	CMOS input capacitance			2		pF
V _{OH}	High-Level Output Voltage		VDD1P8G PIO-0.2			V
V _{OL}	Low-Level Output Voltage				0.2	V
Differential Inputs: SYSREF+/- Mode A						
Clock _{MODE}				PLL Clock Mode Only		
F _{SYSREFMAX}	SYSREF Input Frequency Maximum			40		MHz
V _{SWINGSRMAX}	SYSREF Input Swing Maximum			1.8		Vppdiff ⁽³⁾
V _{SWINGSRMIN}	SYSREF Input Swing Minimum	f _{REF} < 500MHz		0.3		Vppdiff ⁽³⁾
V _{SWINGSRMIN}	SYSREF Input Swing Minimum	f _{REF} > 500MHz		0.6		Vppdiff ⁽³⁾
V _{COMSRMAX}	SYSREF Input Common Mode Voltage Maximum			0.8		V
V _{COMSRMIN}	SYSREF Input Common Mode Voltage Minimum			0.6		V
Z _T	Input termination	differential		100 ⁽¹⁾		Ω
C _L	Input capacitance	Each pin to GND		0.5		pF
LVDS Inputs: 0SYNCIN+/- and 1SYNCIN+/-						
V _{ICOM}	Input Common Voltage			1.2		V
V _{ID}	Differential Input Voltage swing			450		Vppdiff ⁽³⁾
Z _T	Input termination	differential		100		Ω
LVDS Outputs: 0SYNCOUT+/- and 1SYNCOUT+/-						
V _{OCOM}	Output Common Voltage			1.2		V
V _{OD}	Differential Output Voltage swing			500		Vppdiff ⁽³⁾
Z _T	Internal Termination			100		Ω

(1) SYSREF termination is programmable between 100Ω, 150Ω and 300Ω

(2) Loss tolerance is bump to bump from STX to SRX

- (3) V_{ppdiff} is the difference between the maximum differential voltage (positive value) and minimum differential voltage (negative value).

6.8 Power Supply Electrical Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 500MSPS, RX Output Rate = 500MSPS, $f_{\text{DAC}} = 9000\text{MSPS}$ interleave mode; $f_{\text{ADC}} = 3000\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 20Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 1: 4TX TX Dual Band: 96x Int, TX Rate 125 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 1.85 + 2.15\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 2-16-16-1		564		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			274		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLCO			71		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			953		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			1747		mA
P_{diss}	Power Dissipation			4396		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 2: 4TX TX Single Band: 24x Int, TX Rate 500 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 4-8-4-1		570		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			382		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLCO			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			967		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2172		mA
P_{diss}	Power Dissipation			5011		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 3: 4TX TX Single Band: 12x Int, TX Rate 1 GSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 8-8-2-1		571		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			495		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLCO			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			969		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2465		mA
P_{diss}	Power Dissipation			5490		mW

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 500MSPS, RX Output Rate = 500MSPS, $f_{\text{DAC}} = 9000\text{MSPS}$ interleave mode; $f_{\text{ADC}} = 3000\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 20Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 4: 4TX TX Single Band: 8x Int, TX Rate 1500 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 64/66 coding, 24.75Gbps TX: 8-8-2-1		569		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			521		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			73		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			981		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2719		mA
P_{diss}	Power Dissipation			5786		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 5: 2TX TX Single Band: 4x Int, TX Rate 3000 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 64/66 coding, 24.75Gbps TX: 8-4-1-1		297		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			446		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			544		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			1575		mA
P_{diss}	Power Dissipation			3577		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 6: Same as Mode 5 in Sleep mode with Sleep pin pulled high.		96		mA
I_{VDD1P8}	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC+ VDD1P8GPIO + VDDA1P8			330		mA
I_{VDD1P8}	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			16		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			48		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			302		mA
P_{diss}	Power Dissipation			1132		mW

6.9 Timing Requirements

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS, $f_{\text{DAC}} = 8847.36\text{MSPS}$; $f_{\text{ADC}} = 2949.12\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 24.33Gbps; unless otherwise noted.

		MIN	NOM	MAX	UNIT
Timing: SYSREF+/-					
$t_{\text{s}}(\text{SYSREF})$	Setup Time, SYSREF+/- Valid to Rising Edge of CLK+/-		50		ps
$t_{\text{h}}(\text{SYSREF})$	Hold Time, SYSREF+/- Valid after Rising Edge of CLK+/-		50		ps
Timing: Serial ports					
$t_{\text{s}}(\text{SENB})$	Setup Time, SENB to Rising Edge of SCLK			15	ns
$t_{\text{h}}(\text{SENB})$	Hold Time, SENB after last Rising Edge of SCLK ⁽¹⁾		$5 + t_{\text{SCLK}}$		ns
$t_{\text{s}}(\text{SDIO})$	Setup Time, SDIO valid to Rising Edge of SCLK			15	ns
$t_{\text{h}}(\text{SDIO})$	Hold Time, SDIO valid after Rising Edge of SCLK			5	ns
$t_{\text{SCLK_W}}$	Minimum SCLK period: registers write			25	ns
$t_{\text{SCLK_R}}$	Minimum SCLK period: registers read			50	ns
$t_{\text{d}}(\text{data_out})$	Minimum Data Output delay after Falling Edge of SCLK			0	ns
	Maximum Data Output delay after Falling Edge of SCLK			15	ns
t_{RESET}	Minimum RESETZ Pulse Width		1		ms

(1) SDEN\ need to be held one more extra clock cycle with the last SCLK edge

6.10 Switching Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS, $f_{\text{DAC}} = 8847.36\text{MSPS}$; $f_{\text{ADC}} = 2949.12\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 24.33Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
TX Channel Latency						
	SerDes Receiver Analog Delay	Full rate		2.8		ns
$t_{\text{JESD TX}}$	JESD to TX output Latency	LMFSHd=2-8-8-1, 368.64 MSPS input rate, 24x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		152		interface clock cycles ⁽¹⁾
		LMFSHd=8-16-4-1, 491.52 MSPS 24x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		176		
		LMFSHd=4-16-8-1, 245.76 MSPS 48x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		124		
		LMFSHd=2-16-16-1, 122.88 MSPS 96x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		97		

(1) Interface clock cycles is the period of the digital interface sample rate, e.g. 1GSPS = 1ns.

7 Device and Documentation Support

7.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](https://www.ti.com) のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

7.2 サポート・リソース

TI E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、該当する貢献者により、現状のまま提供されるものです。これらは TI の仕様を構成するものではなく、必ずしも TI の見解を反映したものではありません。TI の[使用条件](#)を参照してください。

7.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

7.4 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

7.5 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

8 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
AFE7954IABJ	ACTIVE	FCBGA	ABJ	400	90	RoHS & Green	SNAGCU	Level-3-260C-168 HR	-40 to 85	AFE7954I	Samples
AFE7954IALK	ACTIVE	FCBGA	ALK	400	90	Non-RoHS & Green	Call TI	Level-3-220C-168 HR	-40 to 85	AFE7954 SNPB	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

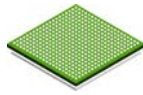
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

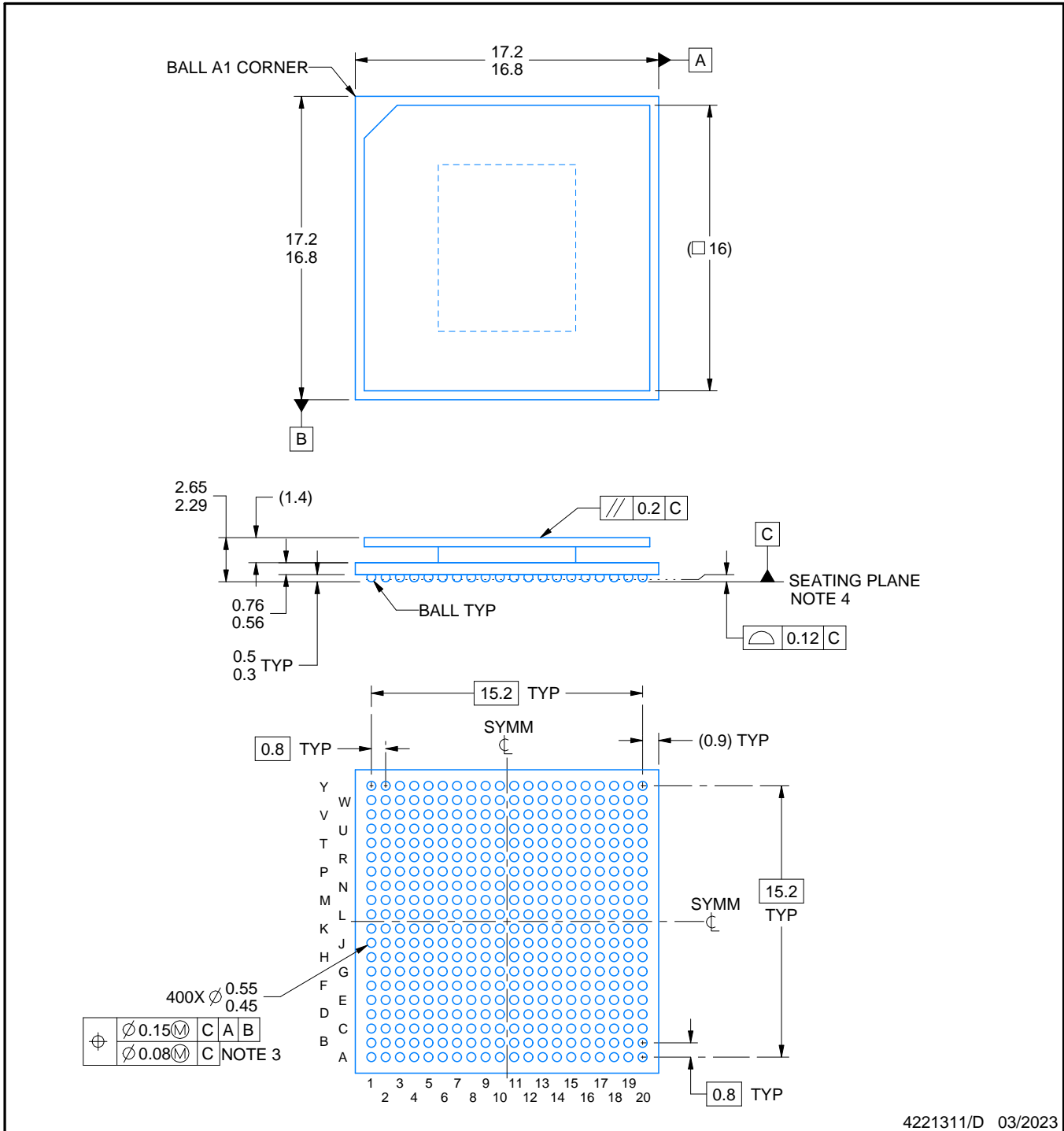
ABJ0400A



PACKAGE OUTLINE

FCBGA - 2.65 mm max height

BALL GRID ARRAY



4221311/D 03/2023

NOTES:

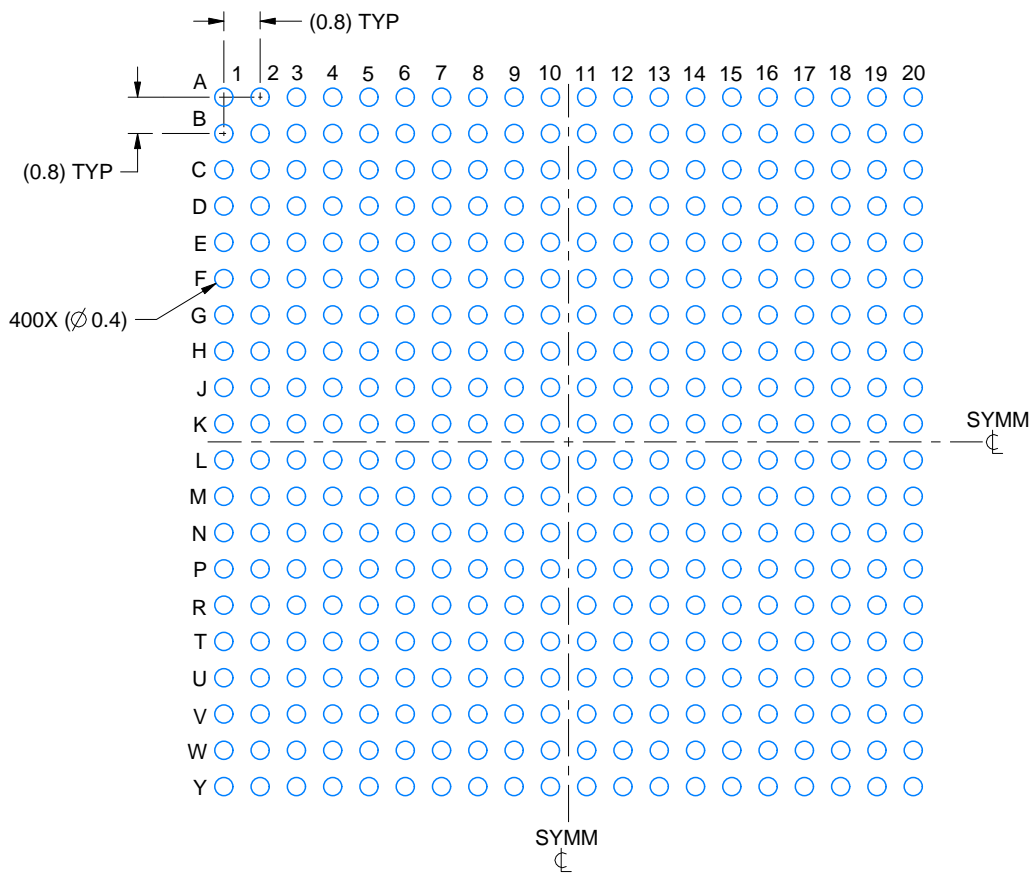
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
5. The lids are electrically floating (e.g. not tied to GND).

EXAMPLE BOARD LAYOUT

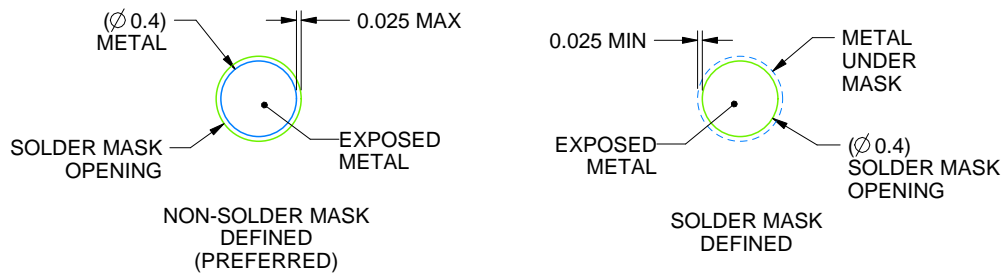
ABJ0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

4221311/D 03/2023

NOTES: (continued)

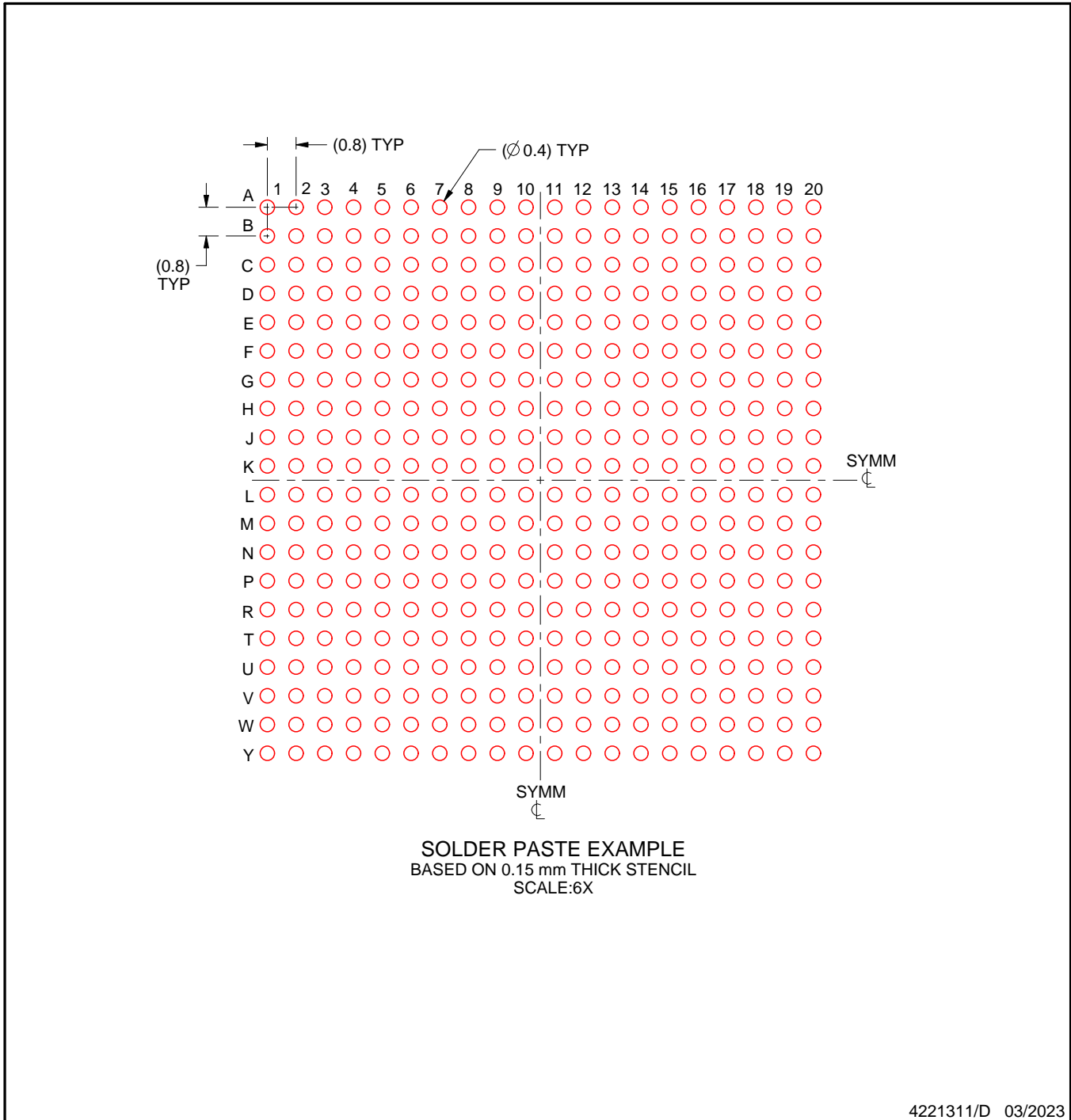
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SPRU811 (www.ti.com/lit/spru811).

EXAMPLE STENCIL DESIGN

ABJ0400A

FCBGA - 2.65 mm max height

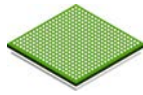
BALL GRID ARRAY



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

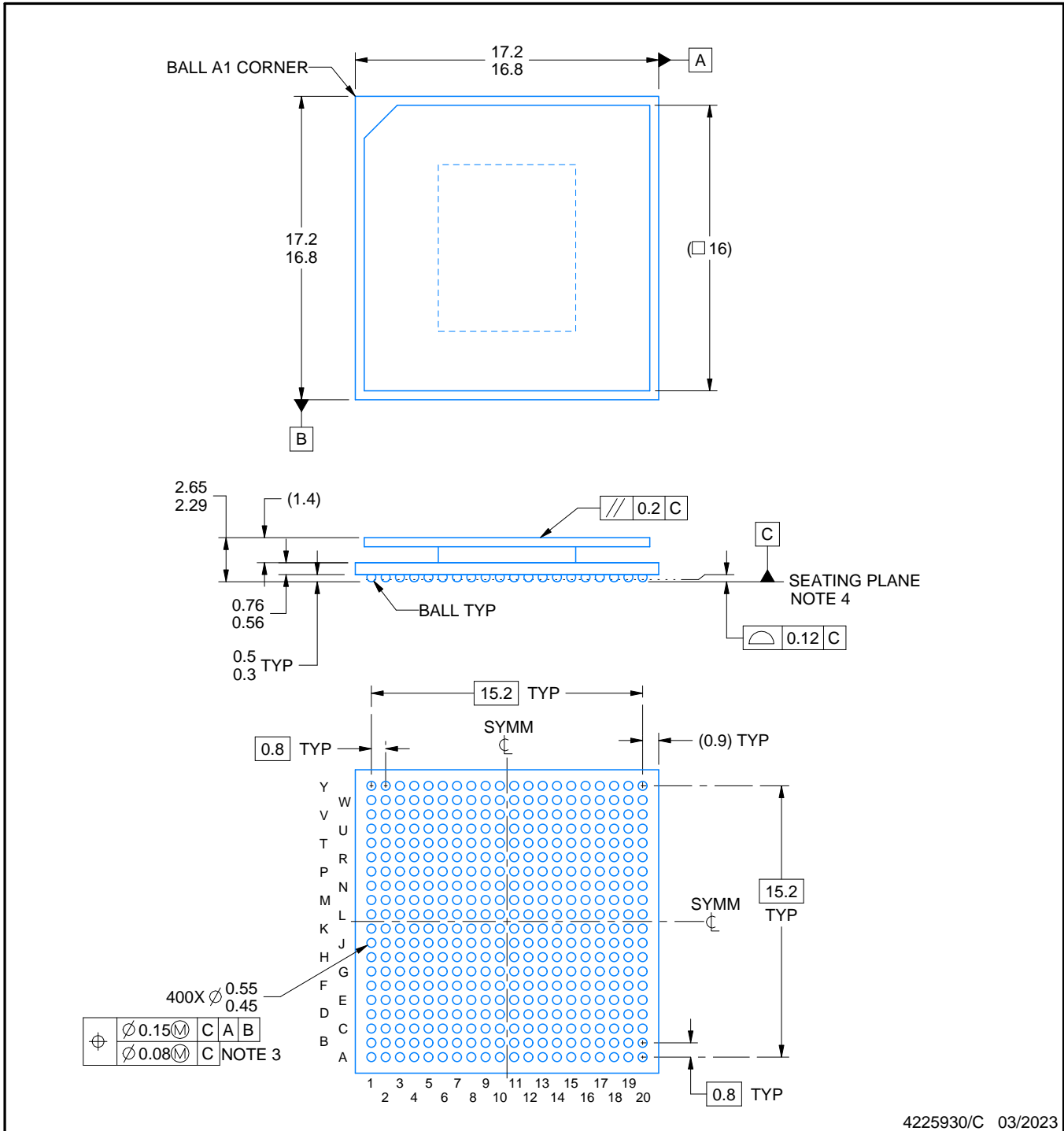
ALK0400A



PACKAGE OUTLINE

FCBGA - 2.65 mm max height

BALL GRID ARRAY



4225930/C 03/2023

NOTES:

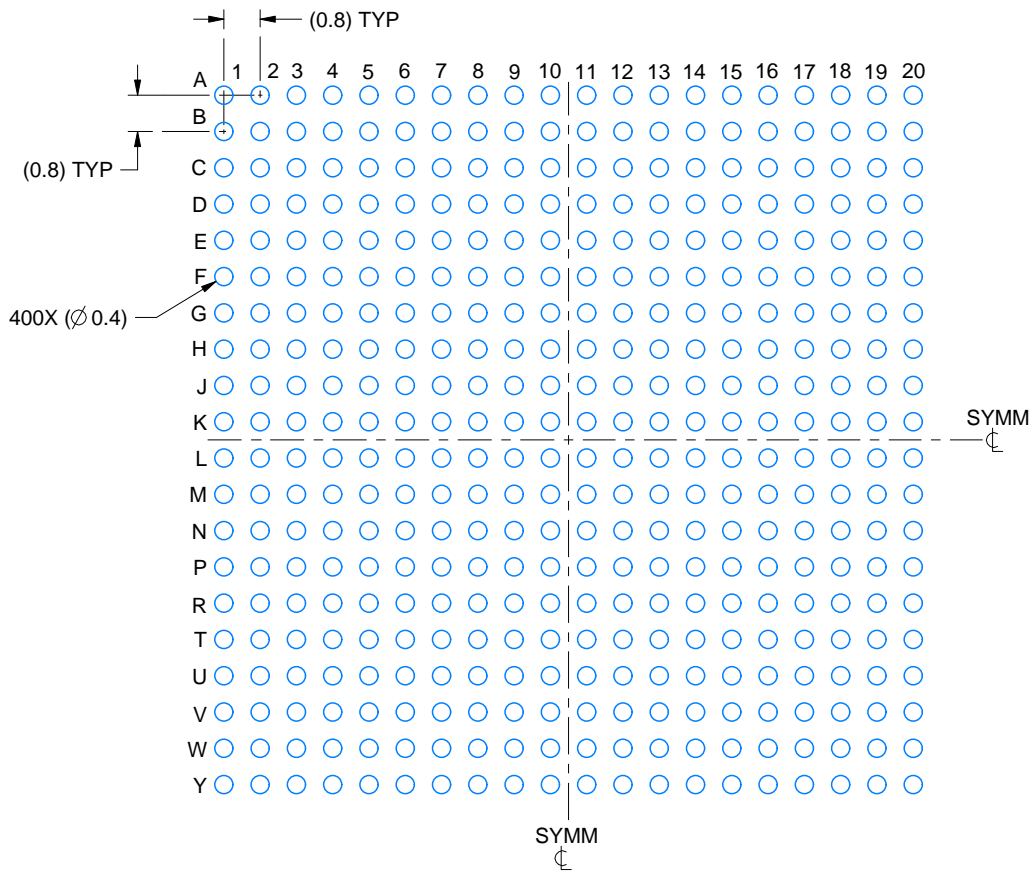
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
5. Pb-Free die bump and SnPb solder ball.
6. The lids are electrically floating (e.g. not tied to GND).

EXAMPLE BOARD LAYOUT

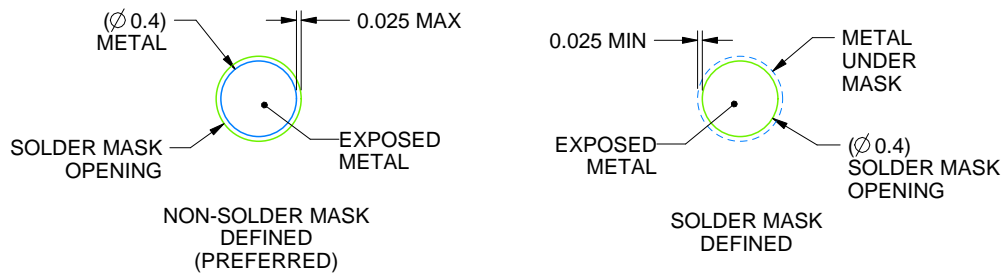
ALK0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

4225930/C 03/2023

NOTES: (continued)

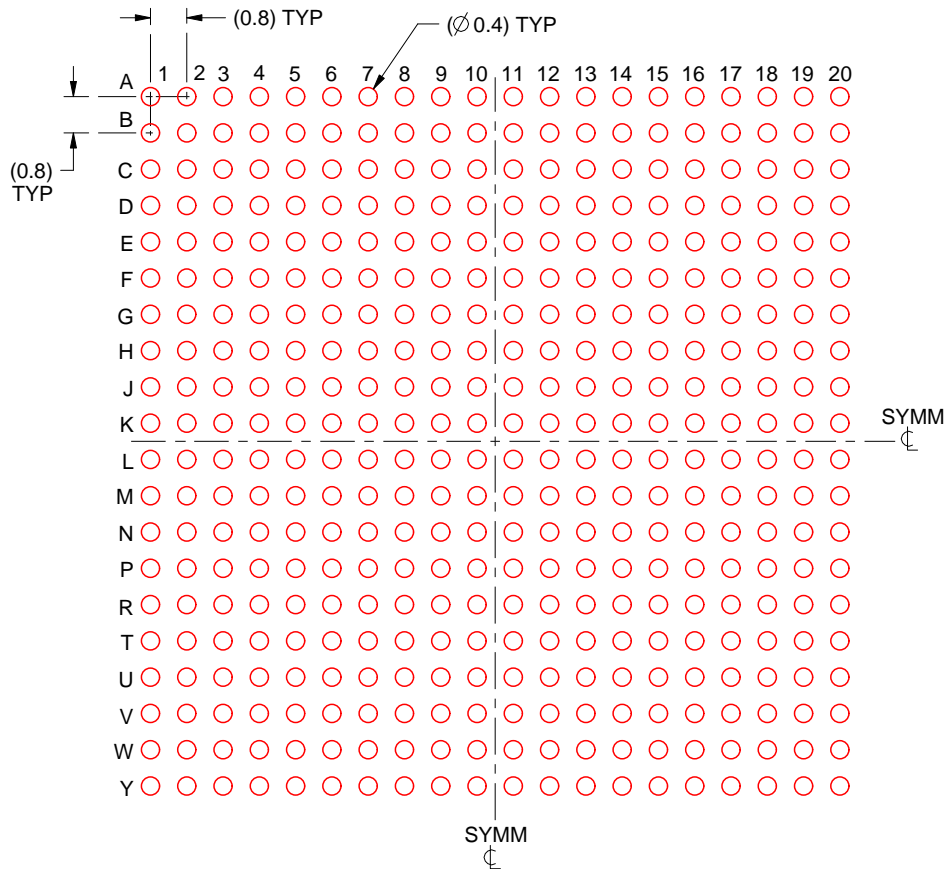
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SPRU811 (www.ti.com/lit/spru811).

EXAMPLE STENCIL DESIGN

ALK0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.15 mm THICK STENCIL
SCALE:6X

4225930/C 03/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

重要なお知らせと免責事項

TI は、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス・デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとし、

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、[TI の販売条件](#)、または [ti.com](https://www.ti.com) やかかる TI 製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、TI はそれらに異議を唱え、拒否します。

郵送先住所 : Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2023, Texas Instruments Incorporated